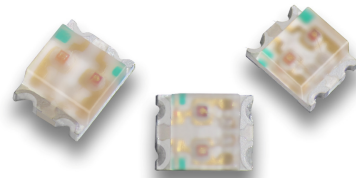


APTB1612ESGC-F01

1.6 x 1.25 mm Bi-Color SMD Chip LED Lamp



DESCRIPTIONS

- The High Efficiency Red source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode
- The Super Bright Green source color devices are made with Gallium Phosphide Green Light Emitting Diode

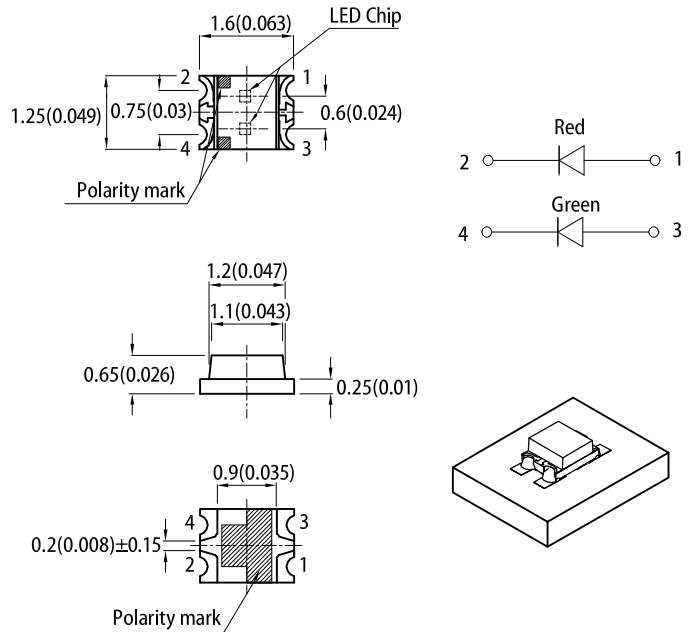
FEATURES

- 1.6 mm x 1.25 mm SMD LED, 0.65 mm thickness
- Bi-color, low power consumption
- Wide viewing angle
- Ideal for backlight and indicator
- Package: 2000 pcs / reel
- Moisture sensitivity level: 3
- Halogen-free
- RoHS compliant

APPLICATIONS

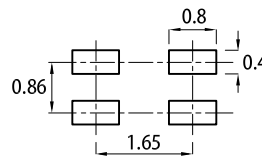
- Backlight
- Status indicator
- Home and smart appliances
- Wearable and portable devices
- Healthcare applications

PACKAGE DIMENSIONS



RECOMMENDED SOLDERING PATTERN

(units : mm; tolerance : ± 0.1)



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ±0.2(0.008") unless otherwise noted.
3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
4. The device has a single mounting surface. The device must be mounted according to the specifications.

SELECTION GUIDE

Part Number	Emitting Color (Material)	Lens Type	Iv (mcd) @ 20mA ^[2]		Viewing Angle ^[1]	
			Min.	Typ.	2θ1/2	
APTB1612ESGC-F01	<div><div></div> High Efficiency Red (GaAsP/GaP)</div>	Water Clear	8	15	150°	
			*3	*7		
	<div><div></div> Super Bright Green (GaP)</div>		5	12		
			*5	*12		

Notes:
1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
2. Luminous intensity / luminous flux: +/-15%.

* Luminous intensity value is traceable to CIE127-2007 standards.

ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

Parameter	Symbol	Emitting Color	Value		Unit
			Typ.	Max.	
Wavelength at Peak Emission I _F = 20mA	λ_{peak}	High Efficiency Red Super Bright Green	627 565	-	nm
Dominant Wavelength I _F = 20mA	$\lambda_{dom}^{[1]}$	High Efficiency Red Super Bright Green	617 568	-	nm
Spectral Bandwidth at 50% Φ REL MAX I _F = 20mA	$\Delta\lambda$	High Efficiency Red Super Bright Green	45 30	-	nm
Capacitance	C	High Efficiency Red Super Bright Green	15 15	-	pF
Forward Voltage I _F = 20mA	V _F ^[2]	High Efficiency Red Super Bright Green	2.0 2.2	2.5 2.5	V
Reverse Current (V _R = 5V)	I _R	High Efficiency Red Super Bright Green	-	10 10	μA
Temperature Coefficient of λ_{peak} I _F = 20mA, -10°C ≤ T ≤ 85°C	TC _{λ_{peak}}	High Efficiency Red Super Bright Green	0.13 0.12	-	nm/°C
Temperature Coefficient of λ_{dom} I _F = 20mA, -10°C ≤ T ≤ 85°C	TC _{λ_{dom}}	High Efficiency Red Super Bright Green	0.06 0.08	-	nm/°C
Temperature Coefficient of V _F I _F = 20mA, -10°C ≤ T ≤ 85°C	TC _V	High Efficiency Red Super Bright Green	-1.9 -2.0	-	mV/°C

Notes:

1. The dominant wavelength (λ_d) above is the setup value of the sorting machine. (Tolerance λ_d : ±1nm.)
2. Forward voltage: ±0.1V.
3. Wavelength value is traceable to CIE127-2007 standards.
4. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

ABSOLUTE MAXIMUM RATINGS at T_A=25°C

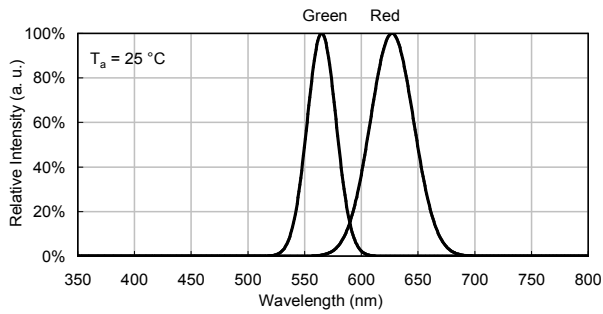
Parameter	Symbol	Value		Unit
		High Efficiency Red	Super Bright Green	
Power Dissipation	P _D	75	62.5	mW
Reverse Voltage	V _R	5	5	V
Junction Temperature	T _J	125	110	°C
Operating Temperature	T _{op}	-40 To +85		°C
Storage Temperature	T _{stg}	-40 To +85		°C
DC Forward Current	I _F	30	25	mA
Peak Forward Current	I _{FM} ^[1]	160	140	mA
Electrostatic Discharge Threshold (HBM)	-	8000	8000	V
Thermal Resistance (Junction / Ambient)	R _{th JA} ^[2]	720	790	°C/W
Thermal Resistance (Junction / Solder point)	R _{th JS} ^[2]	550	620	°C/W

Notes:

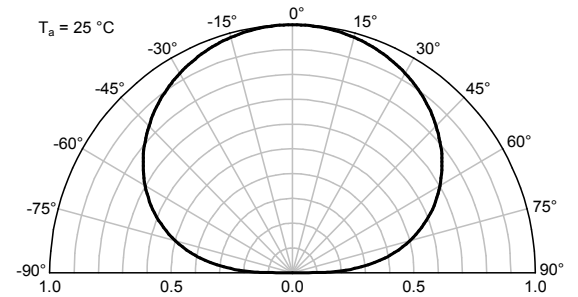
1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. R_{th JA}, R_{th JS} Results from mounting on PC board FR4 (pad size ≥ 16 mm² per pad).
3. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

TECHNICAL DATA

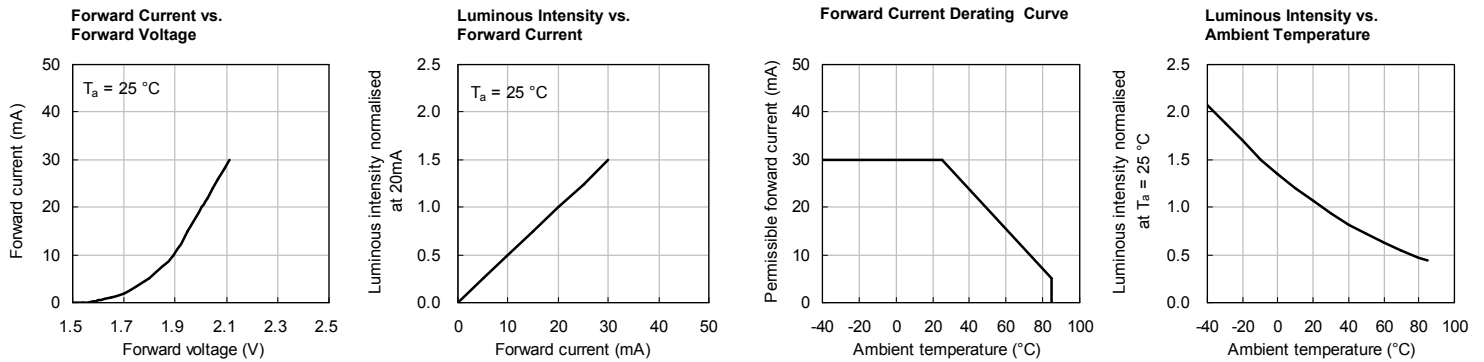
RELATIVE INTENSITY vs. WAVELENGTH



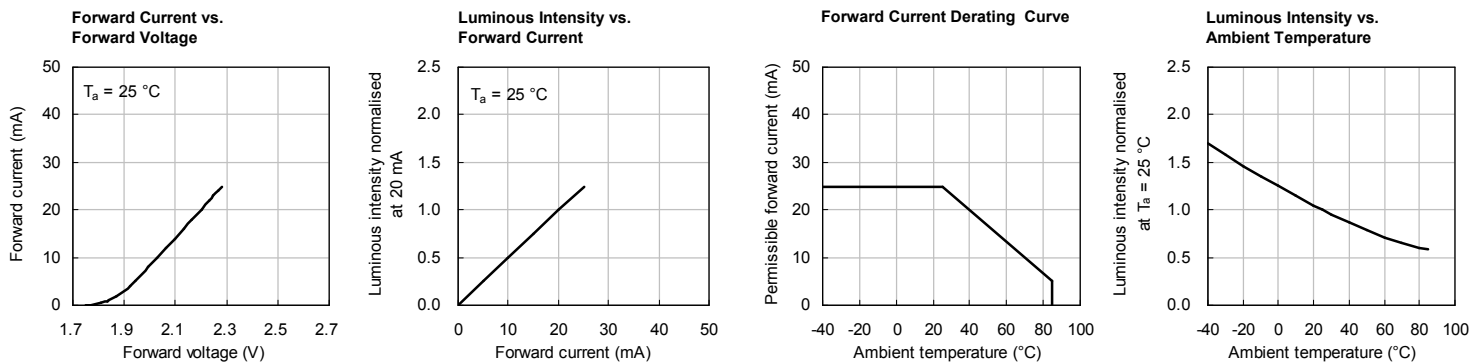
SPATIAL DISTRIBUTION



HIGH EFFICIENCY RED

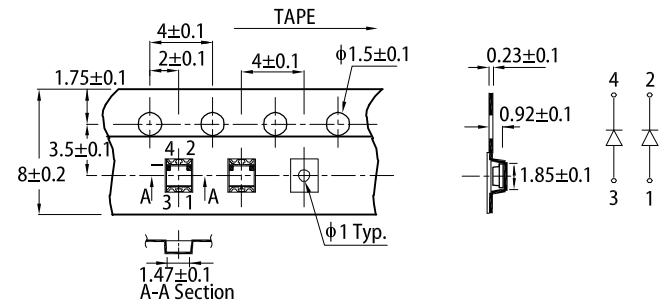
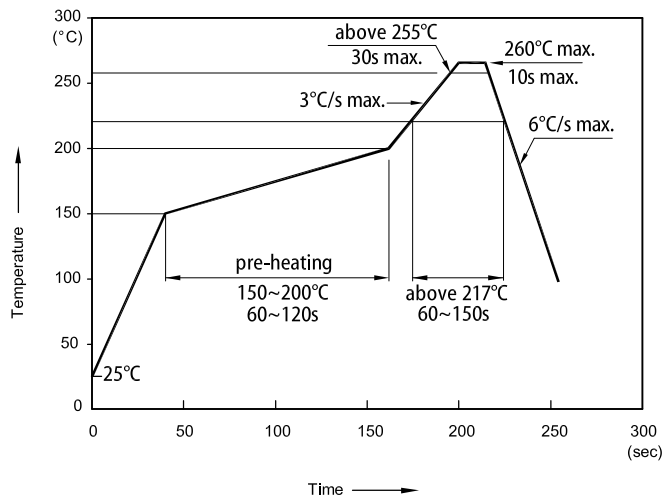


SUPER BRIGHT GREEN

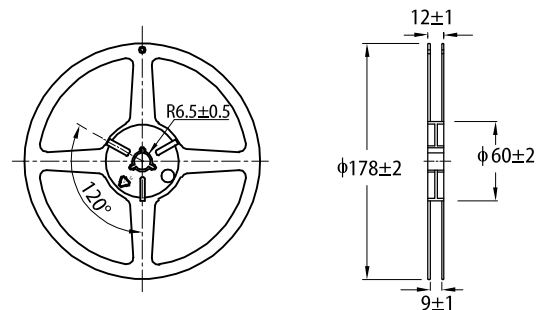


REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS

TAPE SPECIFICATIONS (units : mm)

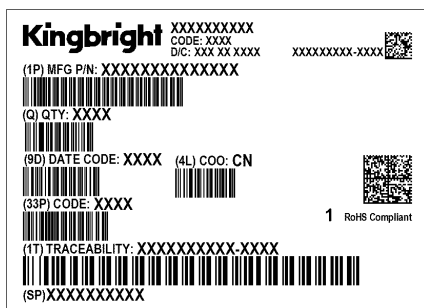
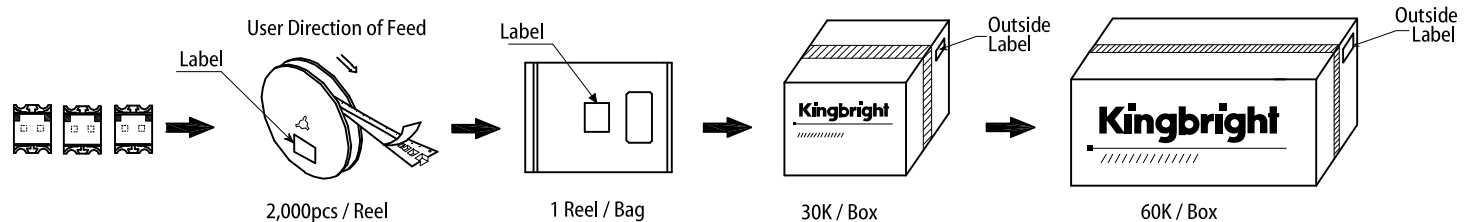


REEL DIMENSION (units : mm)



- Notes:
1. Don't cause stress to the LEDs while it is exposed to high temperature.
 2. The maximum number of reflow soldering passes is 2 times.
 3. Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

PACKING & LABEL SPECIFICATIONS



PRECAUTIONARY NOTES

1. The information included in this document reflects representative usage scenarios and is intended for technical reference only.
2. The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications.
3. When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues.
4. The information in this document applies to typical usage in consumer electronics applications. If customer's application has special reliability requirements or have life-threatening liabilities, such as automotive or medical usage, please consult with Kingbright representative for further assistance.
5. The contents and information of this document may not be reproduced or re-transmitted without permission by Kingbright.
6. All design applications should refer to Kingbright application notes available at <https://www.KingbrightUSA.com/ApplicationNotes>